

GSDSB5819WSF

Schottky Diode

Product Description

Schottky Barrier Diode 40V and 1A


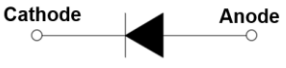
Features

- Low Forward Voltage


Mechanical Data

- SOD-323FL Package
- RoHS Compliant and Halogen Free

Package and Pin Assignment

SOD-323FL		Equivalent Circuit	
			
Pin	Description	Pin	Description
1	Anode	2	Cathode

Ordering and Marking Information

GS P/N	Package	Marking	Quantity / Reel
GSDSB5819WSF	SOD-323FL	SL / ^{SL} •	3,000PCS
GSDSB5819WSF - Product Code: GSDSB5819 - Package Code: WS for SOD-323FL - Green Level: F for RoHS Compliant and Halogen Free			
Marking Information			
		- Product Code: □□ is SL / ^{SL} • - Band denotes Cathode end	

GSDSB5819WSF

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Symbol	Parameter	Value	Unit
V _{R(RM)}	Repetitive Peak Reverse Voltage	40	V
V _{R(RMS)}	RMS Reverse Voltage	28	V
I _O	Forward Current	1	A
I _{FSM}	Non-Repetitive Peak Forward Current (8.3ms single half sin-wave)	9	A
P _D	Power Dissipation	250	mW
T _J	Junction Temperature	125	°C
T _{STG}	Storage Temperature Range	-55 to +125	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{BR}	Breakdown Voltage	I _R =1mA	40			V
V _F	Forward Voltage	I _F =1A			0.6	V
I _R	Reverse Current	V _R =40V			1	mA
C _J	Junction Capacitance	V _R =4V, f=1MHz			120	pF

Typical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

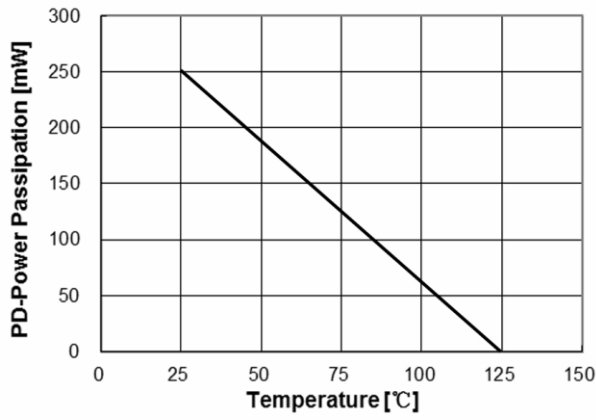


FIG.1 Power Derating Curve

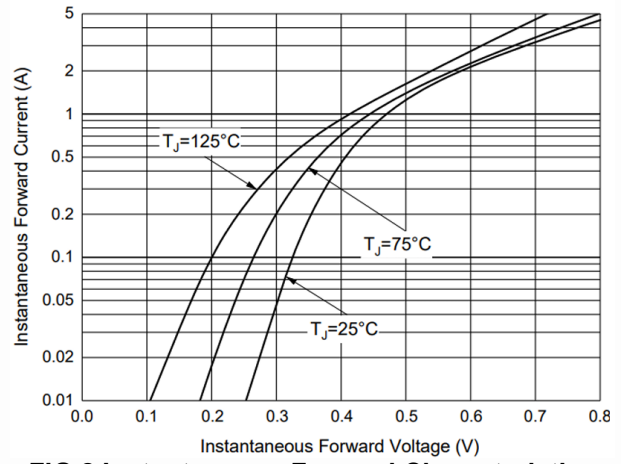
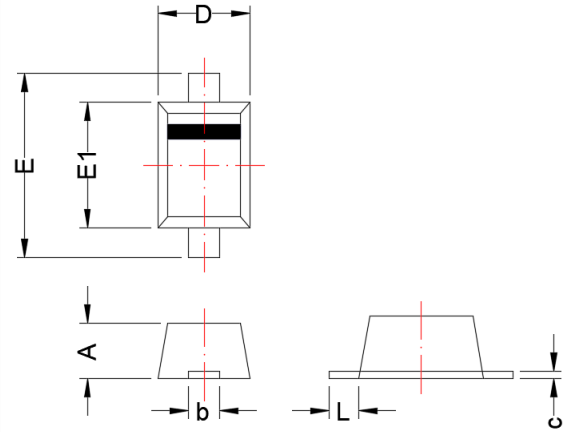


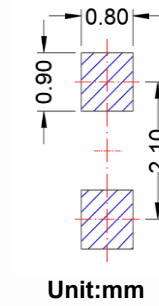
FIG.2 Instantaneous Forward Characteristics

SOD-323FL

Package Dimension



Recommended Land Pattern



Dimensions				
Symbol	Millimeters		Inches	
	Min	Max	Min	Max
A	0.60	1.10	0.023	0.043
b	0.25	0.60	0.010	0.024
c	0.05	0.26	0.002	0.010
D	1.15	1.35	0.045	0.053
E	2.30	2.70	0.091	0.106
E1	1.60	1.80	0.063	0.071
L	0.30	0.50	0.012	0.020





NOTE:



Dimensions are exclusive of Burrs, Mold Flash & Tie Bar extrusions.

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